



# R1200 thru R2000

High Voltage Silicon Rectifiers  
Reverse Voltage 1200 to 2000 Volts Forward Current 0.2 to 0.5 Ampere

## Features

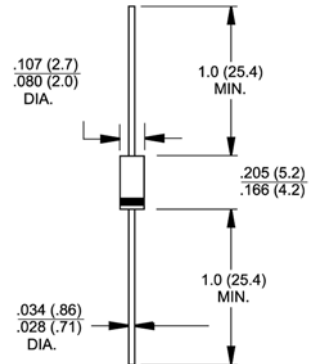
- ◆ Low cost
- ◆ Low leakage
- ◆ Low forward voltage drop
- ◆ High current capability



DO-204AL (DO-41)

## Mechanical Data

- ◆ Case: Molded plastic DO-204AL (DO-41)
- ◆ Epoxy: Device has UL flammability classification 94V-0
- ◆ Lead: MIL-STD-202E method 208C guaranteed
- ◆ Mounting position: Any
- ◆ Weight: 0.012 ounce, 0.335 gram



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Parameter	Symbols	R1200	R1500	R1800	R2000	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	1200	1500	1800	2000	Volts
Maximum RMS voltage	$V_{RMS}$	840	1050	1260	1400	Volts
Maximum DC blocking voltage	$V_{DC}$	1200	1500	1800	2000	Volts
Maximum average forward rectified current at $T_A=50^\circ\text{C}$	$I_{F(AV)}$	500			200	mAmps
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	30.0				Amps
Maximum instantaneous forward voltage at 0.5A/0.2A DC	$V_F$	2.0			3.0	Volts
Maximum DC reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$			5.0 50		$\mu\text{A}$
Maximum full load reverse current average, full cycle .375" (9.5mm) lead length at $T_L=75^\circ\text{C}$	$I_{R(AV)}$	30				$\mu\text{A}$
Typical junction capacitance (Note 1)	$C_J$	30				pF
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150				$^\circ\text{C}$

Notes: 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts.

## RATINGS AND CHARACTERISTIC CURVES

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

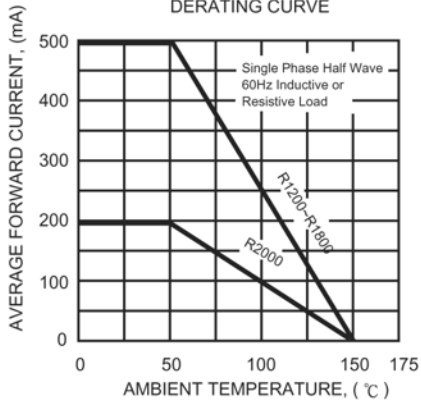


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

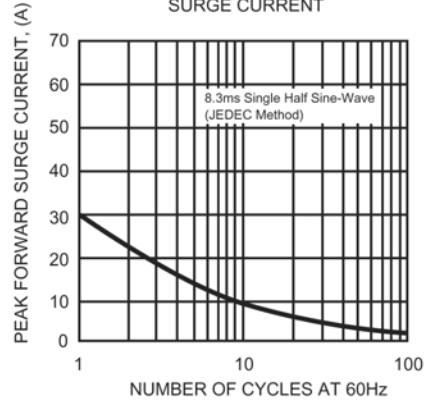


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

